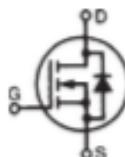


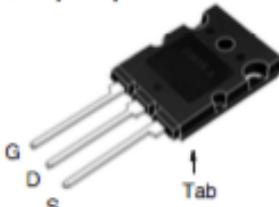
**X2-Class HiPerFET™
Power MOSFET**
**IXFK120N65X2
IXFX120N65X2**

N-Channel Enhancement Mode
Avalanche Rated
Fast Intrinsic Diode

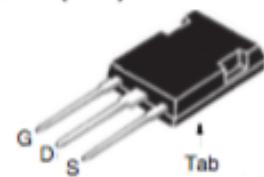


V_{DSS} = 650V
I_{D25} = 120A
R_{DS(on)} ≤ 24mΩ

TO-264P (IXFK)



PLUS247 (IXFX)



G = Gate D = Drain
S = Source Tab = Drain

Symbol	Test Conditions	Maximum Ratings		
V_{DSS}	$T_J = 25^\circ\text{C}$ to 150°C	650		V
V_{GDR}	$T_J = 25^\circ\text{C}$ to 150°C , $R_{GS} = 1\text{M}\Omega$	650		V
V_{GSS}	Continuous	± 30		V
V_{GSM}	Transient	± 40		V
I_{D25}	$T_C = 25^\circ\text{C}$	120		A
I_{DM}	$T_C = 25^\circ\text{C}$, Pulse Width Limited by T_{JM}	240		A
I_A	$T_C = 25^\circ\text{C}$	20		A
E_{AS}	$T_C = 25^\circ\text{C}$	1.5		J
P_0	$T_C = 25^\circ\text{C}$	1250		W
dv/dt	$I_S \leq I_{DM}$, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$	50		V/ns
T_J		-55 ... +150		°C
T_{JM}		150		°C
T_{sig}		-55 ... +150		°C
T_L	Maximum Lead Temperature for Soldering	300		°C
T_{SOLD}	Plastic Body for 10s	260		°C
M_d	Mounting Torque (TO-264)	1.13/10		Nm/lb.in
F_c	Mounting Force (PLUS247)	20..120 /4.5..27		N/lb
Weight	TO-264P	10		g
	PLUS247	6		g

Features

- International Standard Packages
- Low Q_{Gd}
- Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol	Test Conditions ($T_J = 25^\circ\text{C}$ Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
BV_{DSS}	$V_{GS} = 0\text{V}$, $I_D = 3\text{mA}$	650		V
$V_{GS(on)}$	$V_{DS} = V_{GS}$, $I_D = 8\text{mA}$	2.7		5.5 V
I_{GSS}	$V_{GS} = \pm 30\text{V}$, $V_{DS} = 0\text{V}$			± 100 nA
I_{GSS}	$V_{GS} = \pm 30\text{V}$, $V_{DS} = 0\text{V}$			± 100 nA
I_{GSS}	$V_{DS} = V_{DSS}$, $V_{GS} = 0\text{V}$			50 μA
I_{GSS}	$V_{DS} = V_{DSS}$, $V_{GS} = 0\text{V}$			5 mA
$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 0.5 * I_{D25}$, Note 1			24 mΩ



IXFK120N65X2
IXFX120N65X2

Symbol	Test Conditions ($T_J = 25^\circ\text{C}$ Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
g_s	$V_{DS} = 10\text{V}$, $I_D = 0.5 \cdot I_{DSS}$, Note 1	46	76	S
R_{GI}	Gate Input Resistance		0.7	Ω
C_{iss}			15.5	nF
C_{oss}			9.0	nF
C_{rss}			4.2	pF
$t_{d(on)}$			64	ns
t_r			23	ns
$t_{d(off)}$			86	ns
t_f	$V_{GS} = 10\text{V}$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_D = 0.5 \cdot I_{DSS}$, $R_G = 1\Omega$ (External)		12	ns
$Q_{g(on)}$		225	nC	
Q_{gs}		118	nC	
Q_{gd}		66	nC	
R_{thJC}			0.10	$^\circ\text{C}/\text{W}$
R_{thCS}		0.15		$^\circ\text{C}/\text{W}$

Source-Drain Diode

Symbol	Test Conditions ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
I_s	$V_{GS} = 0\text{V}$		120	A
I_{SM}	Repetitive, Pulse Width Limited by T_{JM}		480	A
V_{SD}	$I_F = I_S$, $V_{GS} = 0\text{V}$, Note 1		1.4	V
t_r		240	ns	
Q_{RM}		2.8	μC	
I_{RM}	$V_R = 100\text{V}$, $V_{GS} = 0\text{V}$	23.4	A	

Note 1. Pulse test, $t \leq 300\mu\text{s}$, duty cycle, $d \leq 2\%$.

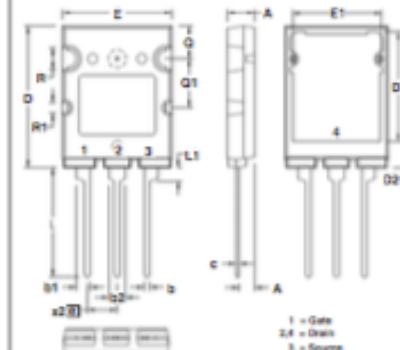
ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

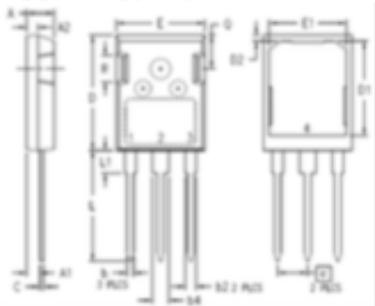
IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592, 4,931,844, 5,049,861, 5,237,481, 6,162,685, 6,404,065 B1, 6,683,344, 6,727,585, 7,005,734 B2, 7,157,338B2, 4,860,072, 5,017,508, 5,083,307, 5,381,025, 6,259,123 B1, 6,534,343, 6,710,405 B2, 6,759,692, 7,063,975 B2, 4,881,106, 5,034,796, 5,187,117, 5,486,715, 6,306,728 B1, 6,583,505, 6,710,463, 6,771,478 B2, 7,071,537

TO-264P Outline



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.185	.209	4.70	5.30
A1	.102	.118	2.60	3.00
b	.035	.049	0.90	1.25
b1	.091	.106	2.30	2.70
b2	.110	.126	2.80	3.20
c	.020	.033	0.50	0.85
D	1.012	1.035	25.70	26.30
D1	.783	.799	19.90	20.30
D2	.205	.205	4.70	5.20
E	.776	.799	19.70	20.50
E1	.661	.677	16.80	17.20
e	.215	BSC	5.46	BSC
L	.768	.807	19.50	20.50
L1	.091	.106	2.30	2.70
O	.228	.244	5.80	6.20
Q1	.346	.362	8.80	9.20
R	.150	.165	3.80	4.20
R1	.071	.087	1.80	2.20

PLUS247™ Outline



Terminals: 1 - Gate
2 - Drain
3 - Source

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b2	.075	.087	1.91	2.20
b4	.115	.126	2.92	3.20
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
D1	.650	.650	16.51	17.53
D2	.075	.075	0.89	1.27
E	.620	.635	15.75	16.13
E1	.520	.540	13.08	14.22
e	.215 BSC		5.45 BSC	
L	.780	.810	19.81	20.57
L1	.150	.170	3.81	4.32
O	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83

